4-Bit Bi-directional Level Shifter for open-drain and Push-Pull Application

Features

- V_{CCA} can be less than, greater than or equal to V_{CCB}
- 1.1V to 3.6V on A Port and 1.1V to 3.6V on B Port
- High-Speed with 24 Mb/s Data Rate for push-pull application
- High-Speed with 2 Mb/s Data Rate for open-drain application
- No Direction-Control Signal Needed
- Low Bit-to-Bit Skew
- Non-preferential Power-up Sequencing
- ESD protection exceeds 8000V HBM per JESD22-A114
- Integrated 10 kΩ Pull-up Resistors
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.
  https://www.diodes.com/quality/product-definitions/
- Packaging (Pb-free & Green):
  - 14-pin, TSSOP (L)
  - 14-pin, 3.5x3.5 mm TQFN (ZB)
  - 12-pin, CSP (GA)

Applications

- I2C, SMBus, MDIO
- Low Voltage ASIC Level Translation
- Mobile Phones, PDAs, Camera

Description

The PI4ULS3V204 is a 4-bit configurable dual supply bidirectional auto sensing translator that does not require a directional control pin. The A and B ports are designed to track two different power supply rails, VCCA and VCCB respectively. Both the VCCA and VCCB supply rails are configurable from 1.1V to 3.6V. This allows voltage logic signals on the VCCA side to be translated into lower, higher or equal value voltage logic signals on the VCCB side, and vice-versa.

The translator has integrated 10 kΩ pull-up resistors on the I/O lines. The integrated pull-up resistors are used to pull-up the I/O lines to either VCCA or VCCB. The PI4ULS3V204 is an excellent match for open-drain applications such as the I2C communication bus.

Block Diagram

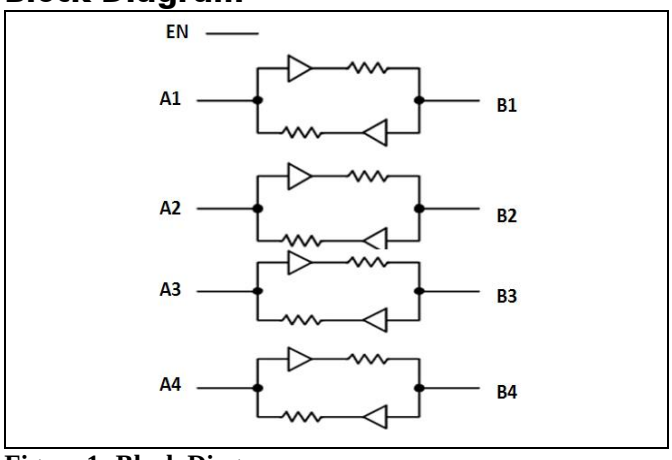
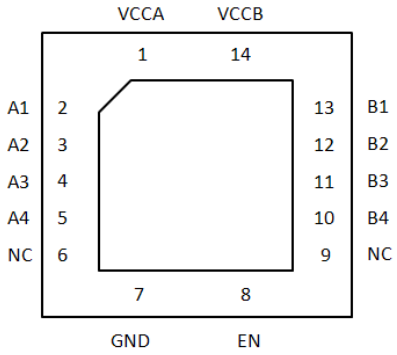


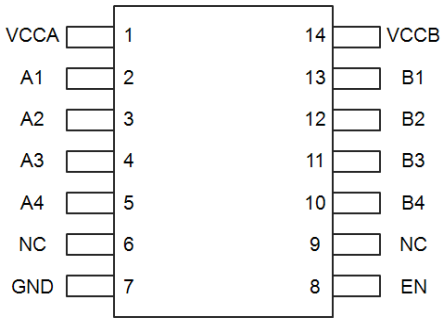
Figure 1: Block Diagram

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

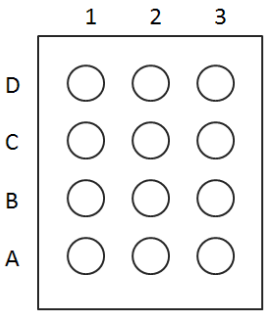
Pin Configuration



TQFN3.5x3.5-14 (Top View)



TSSOP-14 (Top View)



CSP-12 (Top View)

Pin Description

Pin No TSSOP	Pin No TQFN	Pin No CSP	Pin Name	Type	Description
1	1	B2	V_{CCA}	Power	A-port supply voltage. 1.1V ≤ V_{CCA} ≤ 3.6 V
2	2	A3	A1	I/O	Input/output A. Referenced to V_{CCA}.
3	3	B3	A2	I/O	Input/output A. Referenced to V_{CCA}
4	4	C3	A3	I/O	Input/output A. Referenced to V_{CCA}
5	5	D3	A4	I/O	Input/output A. Referenced to V_{CCA}
7	7	D2	GND	GND	Ground.
8	8	C2	EN	Input	Output enable (active High). Pull EN low to place all outputs in 3-state mode.
10	10	D1	B4	I/O	Input/output B. Referenced to V_{CCB}
11	11	C1	B3	I/O	Input/output B. Referenced to V_{CCB}
12	12	B1	B2	I/O	Input/output B. Referenced to V_{CCB}
13	13	A1	B1	I/O	Input/output B. Referenced to V_{CCB}
14	14	A2	V_{CCB}	Power	B-port supply voltage. 1.1 V ≤ V_{CCB} ≤ 3.6V
6, 9	6, 9	/	NC	NC	Not Connect

Maximum Ratings

Storage Temperature	-65°C to +150°C
DC Supply Voltage Port B	-0.3V to +5.5V
DC Supply Voltage Port A	-0.3V to+5.5V
Vi(A) referenced DC Input / Output Voltage	-0.3V to +5.5V
Vi(B) referenced DC Input / Output Voltage	-0.3V to+5.5V
Enable Control Pin DC Input Voltage	-0.3V to+5.5V
Short Circuit duration (I/O to GND)	40mA

Note:
Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operation Conditions

Symbol	Parameter	Min	Typ	Max	Unit
V_{CCA}	V_{CCA} Positive DC Supply Voltage	1.1	-	3.6	V
V_{CCB}	V_{CCB} Positive DC Supply Voltage	1.1	-	3.6	V
V_{EN}	Enable Control Pin Voltage	GND	-	3.6	V
V_{IO}	I/O Pin Voltage	GND	-	3.6	V
$\Delta t / \Delta V$	Input Transition Rise or Fall Time	-	-	10	ns/V
T_A	Operating Temperature Range	−40	-	+85	℃

DC Electrical Characteristics

Unless otherwise specified, -40°C≤T_A≤85°C, 1.1V≤Vcc≤3.6V

Symbol	Parameter	Test Conditions		Min	Typ	Max	Unit
V_{IHB}	B port Input HIGH Voltage	2.3V≤$V_{CC(B)}$ ≤3.6V		V_{CCB} − 0.4	-	-	V
		1.5V≤$V_{CC(B)}$ <2.3V		V_{CCB} − 0.2			V
		1.1V≤$V_{CC(B)}$ <1.5V		V_{CCB} − 0.1			V
V_{ILB}	B port Input LOW Voltage				-	0.15	V
V_{IHA}	A port Input HIGH Voltage	2.3V≤$V_{CC(A)}$ ≤3.6V		V_{CCA}− 0.4			V
		1.5V≤$V_{CC(A)}$ <2.3V		V_{CCA}− 0.2			V
		1.1V≤$V_{CC(A)}$ <1.5V		V_{CCA} − 0.1			V
V_{ILA}	A port Input LOW Voltage	-		-	-	0.15	V
$V_{IH(EN)}$	Control Pin Input HIGH Voltage	1.5V<$V_{CC(A)}$≤3.6V		0.65*V_{CCA}	-	-	V
		1.1V≤$V_{CC(A)}$ ≤1.5V		0.6*V_{CCA}			V
$V_{IL(EN)}$	Control Pin Input LOW Voltage	1.5V<$V_{CC(A)}$≤3.6V		-	-	0.35* V_{CCA}	V
		1.1V≤$V_{CC(A)}$ ≤1.5V				0.2* V_{CCA}	V
V_{OHB}	B port Output HIGH Voltage	B port source current = -20 µA		0.8*V_{CCB}	-	-	V
V_{OLB}	B port Output LOW Voltage	B port sink current =1 mA		-	-	0.4	V
V_{OHA}	A port Output HIGH Voltage	A port source current= -20 µA		0.8* V_{CCA}	-	-	V
V_{OLA}	A port Output LOW Voltage	A port sink current =1 mA		-	-	0.4	V
I_{CCB}	V_{CCB} Supply Current	V_I= V_{CCI}; I_O= 0A; EN= Low or High	$V_{CC(A)}$=1.1V to 3.6V, $V_{CC(B)}$=1.1V to 3.6V	-	1.0	3	µA
			VCCA=1.1V,VCCB=1.8V	-	0.6	2	µA
			VCCA=1.8V, VCCB=3.3V	-	0.7	2	µA
			$V_{CC(A)}$= 3.6V, $V_{CC(B)}$= 0V	-		1	µA
			$V_{CC(A)}$= 0V, $V_{CC(B)}$=3.6V	-		1	µA
I_{CCA}	V_{CCA} Supply Current	V_I= V_{CCI}; I_O= 0A; EN= Low or High	$V_{CC(A)}$=1.1V to 3.6V, $V_{CC(B)}$=1.1V to 3.6V	-	0.2	1	µA
			$V_{CC(A)}$= 3.6V, $V_{CC(B)}$= 0V	-	-	1	µA
			$V_{CC(A)}$= 0V, $V_{CC(B)}$=3.6V	-	-	1	µA

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
I_{OZ}	I/O Tri−state Output Mode Leakage Current	-	-	0.1	1.0	µA
I_{I-EN}	Control pin leakage Current	V_I= V_{CCI} or GND	-	-	1	µA
R_{PU}	Pull−Up Resistors I/O A and B	-	-	10	-	kΩ
C_i	EN	$V_{CC(A)}$= 3.3V, $V_{CC(B)}$= 3.3V	-	-	0.5	pF
C_{iO}	A port	$V_{CC(A)}$= 3.3V, $V_{CC(B)}$= 3.3V	-	-	5	pF
	B port	$V_{CC(A)}$= 3.3V, $V_{CC(B)}$= 3.3V	-	-	5	pF

Note: All units are production tested at T_A = +25℃. Limits over the operating temperature range are guaranteed by design.
Typical values are for V_{CCB} = +2.8 V, V_{CCA} = +1.8 V and T_A = +25℃.

AC Electrical Characteristics

Timing Characteristics – Rail-to-Rail Driving Configuration (I/O test circuits of Figures 2, 3 and 7, C_{LOAD} = 15 pF, driver output impedance ≤ 50Ω, R_{LOAD} = 1 MΩ, T_A = -40℃ to 85℃, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{CCA}= 1.2V±0.1V , V_{CCB} = 1.8V±0.15V						
t_{RB}	B port Rise Time	-			20	nS
t_{FB}	B port Fall Time	-			25	nS
t_{RA}	A port Rise Time	-			20	nS
t_{FA}	A port Fall Time	-			20	nS
t_{EN}	Enable Time	-			200	nS
t_{DIS}	Disable Time	-			200	nS
$t_{PHL−A−B}$	Propagation Delay (Driving A)	-			9	nS
$t_{PLH−A−B}$		-			11	nS
$t_{PHL−B−A}$	Propagation Delay (Driving B)	-			9	nS
$t_{PLH−B−A}$		-			10	nS
t_{PPSKEW}	Part−to−Part Skew	-			1	nS
MDR	Maximum Data Rate	-			20	Mbps
V_{CCA}= 1.2V±0.1V , V_{CCB} = 2.5V±0.2V						
t_{RB}	B port Rise Time	-			12	nS
t_{FB}	B port Fall Time	-			14	nS
t_{RA}	A port Rise Time	-			20	nS
t_{FA}	A port Fall Time	-			25	nS
t_{EN}	Enable Time	-			200	nS
t_{DIS}	Disable Time	-			200	nS
$t_{PHL−A−B}$	Propagation Delay (Driving A)	-			9	nS
$t_{PLH−A−B}$		-			11	nS
$t_{PHL−B−A}$	Propagation Delay (Driving B)	-			9	nS
$t_{PLH−B−A}$		-			10	nS
t_{PPSKEW}	Part−to−Part Skew	-			1	nS
MDR	Maximum Data Rate	-			20	Mbps
V_{CCA}= 1.2V±0.1V , V_{CCB} = 3.3V±0.3V						
t_{RB}	B port Rise Time	-			12	nS
t_{FB}	B port Fall Time	-			18	nS
t_{RA}	A port Rise Time	-			16	nS
t_{FA}	A port Fall Time	-			30	nS
t_{EN}	Enable Time	-			200	nS
t_{DIS}	Disable Time	-			200	nS
$t_{PHL−A−B}$	Propagation Delay (Driving A)	-			8	nS
$t_{PLH−A−B}$		-			11	nS

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
$t_{PHL-B-A}$	Propagation Delay (Driving B)	-			8	nS
$t_{PLH-B-A}$		-			10	nS
t_{PPSKEW}	Part−to−Part Skew	-			1	nS
MDR	Maximum Data Rate	-			20	Mbps
V_{CCA}= 1.8V±0.15V , V_{CCB} = 1.2V±0.1V						
t_{RB}	B port Rise Time	-			25	nS
t_{FB}	B port Fall Time	-			25	nS
t_{RA}	A port Rise Time	-			14	nS
t_{FA}	A port Fall Time	-			25	nS
t_{EN}	Enable Time	-			200	nS
t_{DIS}	Disable Time	-			200	nS
$t_{PHL-A-B}$	Propagation Delay (Driving A)	-			10	nS
$t_{PLH-A-B}$		-			15	nS
$t_{PHL-B-A}$	Propagation Delay (Driving B)	-			12	nS
$t_{PLH-B-A}$		-			12	nS
t_{PPSKEW}	Part-to-Part Skew	-			1	nS
MDR	Maximum Data Rate	-			20	Mbps
V_{CCA}= 1.8V±0.15V, V_{CCB} = 2.5V±0.2V						
t_{RB}	B port Rise Time	-			8	nS
t_{FB}	B port Fall Time	-			8	nS
t_{RA}	A port Rise Time	-			6	nS
t_{FA}	A port Fall Time	-			12	nS
t_{EN}	Enable Time	-			200	nS
t_{DIS}	Disable Time	-			150	nS
$t_{PHL-A-B}$	Propagation Delay (Driving A)	-			5	nS
$t_{PLH-A-B}$		-			4	nS
$t_{PHL-B-A}$	Propagation Delay (Driving B)	-			4	nS
$t_{PLH-B-A}$		-			4	nS
t_{PPSKEW}	Part−to−Part Skew	-			1	nS
MDR	Maximum Data Rate	-			24	Mbps
V_{CCA}= 1.8V±0.15V, V_{CCB} = 3.3V±0.3V						
t_{RB}	B port Rise Time	-			8	nS
t_{FB}	B port Fall Time	-			8	nS
t_{RA}	A port Rise Time	-			4	nS
t_{FA}	A port Fall Time	-			10	nS
t_{EN}	Enable Time	-			180	nS
t_{DIS}	Disable Time	-			120	nS
$t_{PHL-A-B}$	Propagation Delay (Driving A)	-			6	nS
$t_{PLH-A-B}$		-			4	nS
$t_{PHL-B-A}$	Propagation Delay (Driving B)	-			4	nS
$t_{PLH-B-A}$		-			4	nS
t_{PPSKEW}	Part−to−Part Skew	-			1	nS
MDR	Maximum Data Rate	-			24	Mbps

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{CCA}= 2.5V±0.2V , V_{CCB} = 1.2V±0.1V						
t_{RB}	B port Rise Time	-			25	nS
t_{FB}	B port Fall Time	-			30	nS
t_{RA}	A port Rise Time	-			12	nS
t_{FA}	A port Fall Time	-			30	nS
t_{EN}	Enable Time	-			200	nS
t_{DIS}	Disable Time	-			180	nS
$t_{PHL-A-B}$	Propagation Delay (Driving A)	-			10	nS
$t_{PLH-A-B}$		-			14	nS
$t_{PHL-B-A}$	Propagation Delay (Driving B)	-			20	nS
$t_{PLH-B-A}$		-			12	nS
t_{PPSKEW}	Part-to-Part Skew	-			1	nS
MDR	Maximum Data Rate	-			20	Mbps
V_{CCA}= 2.5V±0.2V, V_{CCB} = 1.8V±0.15V						
t_{RB}	B port Rise Time	-			8	nS
t_{FB}	B port Fall Time	-			9	nS
t_{RA}	A port Rise Time	-			9	nS
t_{FA}	A port Fall Time	-			9	nS
t_{EN}	Enable Time	-			200	nS
t_{DIS}	Disable Time	-			120	nS
$t_{PHL-A-B}$	Propagation Delay (Driving A)	-			3	nS
$t_{PLH-A-B}$		-			2	nS
$t_{PHL-B-A}$	Propagation Delay (Driving B)	-			5	nS
$t_{PLH-B-A}$		-			5	nS
t_{PPSKEW}	Part−to−Part Skew	-			1	nS
MDR	Maximum Data Rate	-			24	Mbps
V_{CCA}= 2.5V±0.2V, V_{CCB} = 3.3V±0.3V						
t_{RB}	B port Rise Time	-			7	nS
t_{FB}	B port Fall Time	-			8	nS
t_{RA}	A port Rise Time	-			4	nS
t_{FA}	A port Fall Time	-			10	nS
t_{EN}	Enable Time	-			200	nS
t_{DIS}	Disable Time	-			120	nS
$t_{PHL-A-B}$	Propagation Delay (Driving A)	-			3	nS
$t_{PLH-A-B}$		-			5	nS
$t_{PHL-B-A}$	Propagation Delay (Driving B)	-			4	nS
$t_{PLH-B-A}$		-			4	nS
t_{PPSKEW}	Part−to−Part Skew	-			1	nS
MDR	Maximum Data Rate	-			24	Mbps
V_{CCA}= 3.3V±0.3V , V_{CCB} = 1.2V±0.1V						
t_{RB}	B port Rise Time	-			26	nS
t_{FB}	B port Fall Time	-			32	nS
t_{RA}	A port Rise Time	-			12	nS
t_{FA}	A port Fall Time	-			40	nS
t_{EN}	Enable Time	-			120	nS
t_{DIS}	Disable Time	-			300	nS
$t_{PHL-A-B}$	Propagation Delay	-			10	nS

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
$t_{PLH-A-B}$	(Driving A)	-			14	nS
$t_{PHL-B-A}$	Propagation Delay (Driving B)	-			25	nS
$t_{PLH-B-A}$		-			12	nS
t_{PPSKEW}	Part-to-Part Skew	-			1	nS
MDR	Maximum Data Rate	-			20	Mbps
V_{CCA}= 3.3V±0.3V, V_{CCB} = 1.8V±0.15V						
t_{RB}	B port Rise Time	-			6	nS
t_{FB}	B port Fall Time	-			11	nS
t_{RA}	A port Rise Time	-			6	nS
t_{FA}	A port Fall Time	-			7	nS
t_{EN}	Enable Time	-			120	nS
t_{DIS}	Disable Time	-			200	nS
$t_{PHL-A-B}$	Propagation Delay (Driving A)	-			4	nS
$t_{PLH-A-B}$		-			4	nS
$t_{PHL-B-A}$	Propagation Delay (Driving B)	-			5	nS
$t_{PLH-B-A}$		-			5	nS
t_{PPSKEW}	Part−to−Part Skew	-			1	nS
MDR	Maximum Data Rate	-			24	Mbps
V_{CCA}= 3.3V±0.3V, V_{CCB} = 2.5V±0.2V						
t_{RB}	B port Rise Time	-			6	nS
t_{FB}	B port Fall Time	-			10	nS
t_{RA}	A port Rise Time	-			6	nS
t_{FA}	A port Fall Time	-			7	nS
t_{EN}	Enable Time	-			120	nS
t_{DIS}	Disable Time	-			200	nS
$t_{PHL-A-B}$	Propagation Delay (Driving A)	-			4	nS
$t_{PLH-A-B}$		-			4	nS
$t_{PHL-B-A}$	Propagation Delay (Driving B)	-			4	nS
$t_{PLH-B-A}$		-			4	nS
t_{PPSKEW}	Part−to−Part Skew	-			1	nS
MDR	Maximum Data Rate	-			24	Mbps

Timing Characteristics – Open Drain Driving Configuration

($1.1 \leq V_{CCA} \leq V_{CCB} \leq 3.6V$, T_A = -40℃ to 85℃)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
t_{RB}	B port Rise Time	-	-	-	300	nS
t_{FB}	B port Fall Time	-	-	-	30	nS
t_{RA}	A port Rise Time	-	-	-	300	nS
t_{FA}	A port Fall Time	-	-	-	30	nS
$t_{PHL-A-B}$	Propagation Delay (Driving A)	-	-	-	20	nS
$t_{PLH-A-B}$		-	-	-	260	nS
$t_{PHL-B-A}$	Propagation Delay (Driving B)	-	-	-	20	nS
$t_{PLH-B-A}$		-	-	-	260	nS
t_{PPSKEW}	Part-to-Part Skew	-	-	-	1	nS
MDR	Maximum Data Rate	-	2	-	-	Mbps

Test Circuits

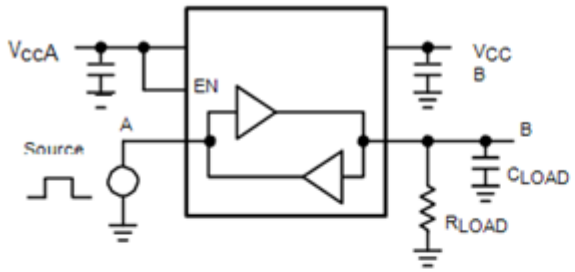


Figure 2.Rail-to-Rail Driving A

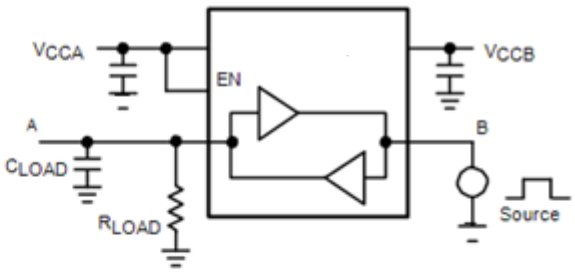


Figure 3. Rail-to-Rail Driving B

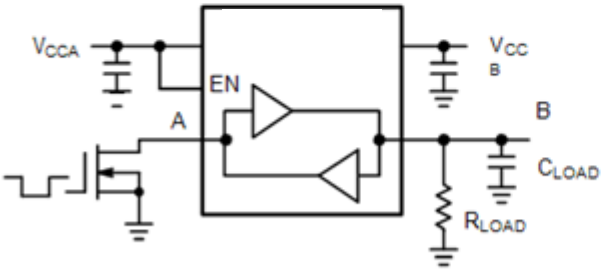


Figure 4. Open-Drain Driving A

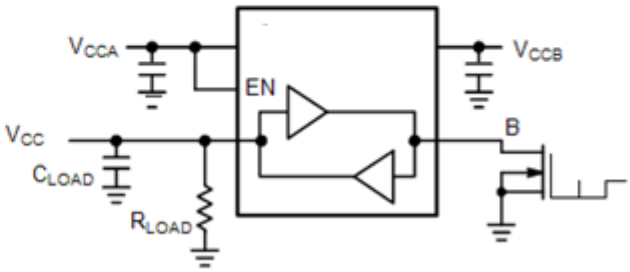
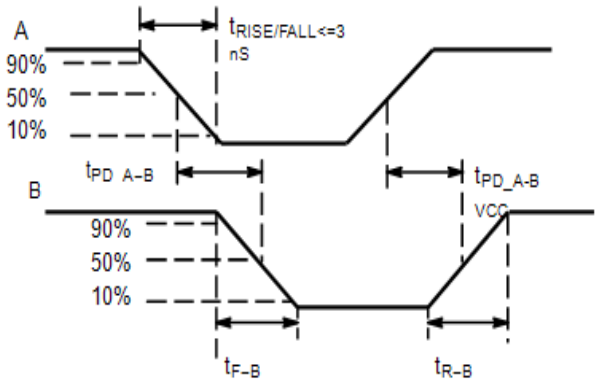


Figure 5. Open-Drain Driving B



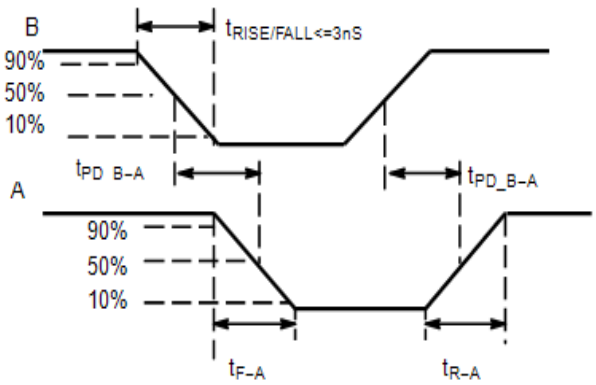
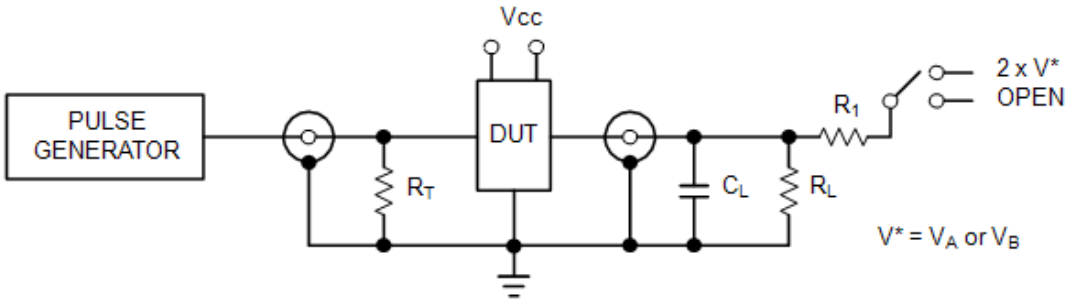


Figure 6. Definition of Timing Specification Parameters



Test	Switch
t_{PZH}, t_{PHZ}	Open
t_{PZL}, t_{PLZ}	2 x V*

C_L = 15 pF or equivalent (Includes jig and probe capacitance)
R_L = R_1 = 50 kΩ or equivalent
R_T = Z_{OUT} of pulse generator (typically 50 Ω)
V* = V_A or V_B for A or B measurements,
respectively.

Figure 7. Test Circuit for Enable/Disable Time Measurement

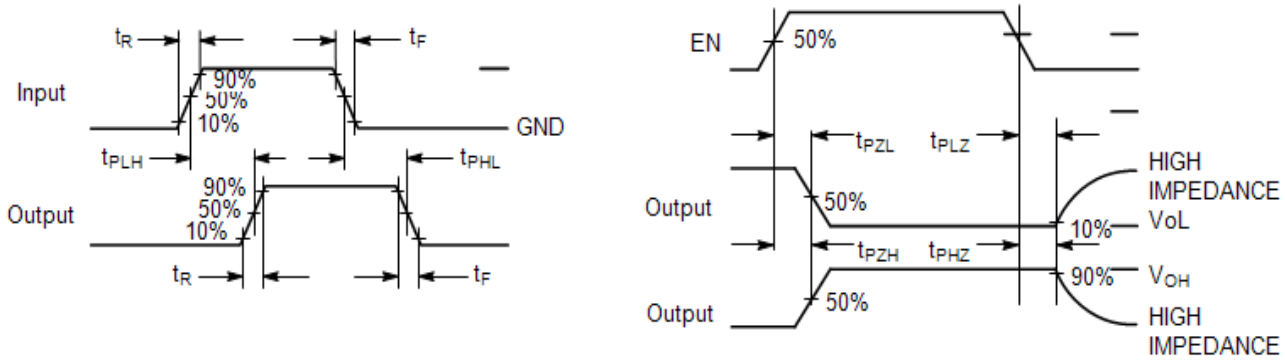


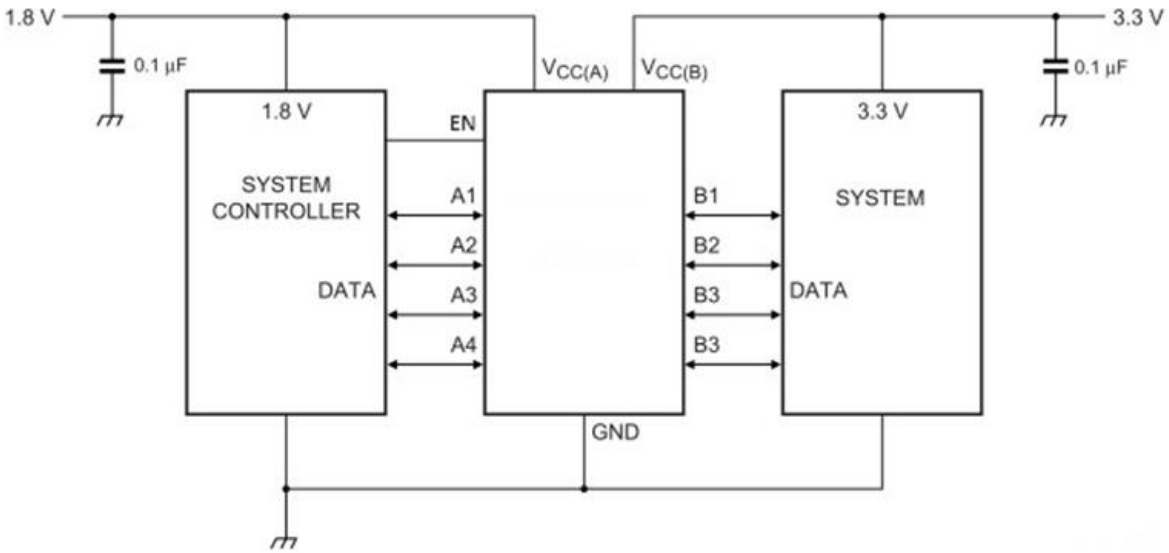
Figure 8. Timing Definitions for Propagation Delays and Enable/Disable Measurement

Functional Description

The PI4ULS3V204 is a 4−bit configurable dual−supply bidirectional auto sensing translator that does not require a directional control pin. The A and B ports are designed to track two different power supply rails, V_{CCA} and V_{CCB} respectively. Both the V_{CCA} and V_{CCB} supply rails are configurable from 1.1 V to 3.6V. This allows voltage logic signals on the V_{CCA} side to be translated into lower, higher or equal value voltage logic signals on the V_{CCB} side, and vice−versa.

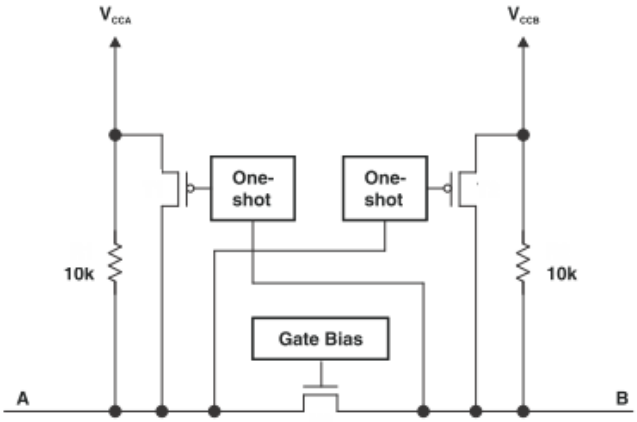
The translator has integrated 10 kΩ pull−up resistors on the I/O lines. The integrated pull−up resistors are used to pull−up the I/O lines to either V_{CCA} or V_{CCB}. The PI4ULS3V204 is an excellent match for open−drain applications such as the I^2C communication bus.

Application Information



Level Translator Architecture

The PI4ULS3V204 auto sense translator provides bidirectional voltage level shifting to transfer data in multiple supply voltage systems. This device has two supply voltages, V_{CCA} and V_{CCB}, which set the logic levels on the input and output sides of the translator. When used to transfer data from A port to B port, input signals referenced to the V_{CCA} supply are translated to output signals with a logic level matched to V_{CCB}. In a similar manner, translation shifts input signals with a logic level compatible to V_{CCB} to an output signal matched to V_{CCA}. The PI4ULS3V204 consists of two bidirectional channels that independently determine the direction of the data flow without requiring a directional pin. The one-shot circuits are used to detect the rising or falling input signals. In addition, the one shots decrease the rise and fall time of the output signal for high-to-low and low-to-high transitions. Each input/output channel has an internal 10 kΩ pull. The magnitude of the pull-up resistors can be reduced by connecting external resistors in parallel to the internal 10 kΩ resistors.



Input Driver Requirements

The rise (tR) and fall (tF) timing parameters of the open drain outputs depend on the magnitude of the pull–up resistors. In-addition, the propagation times (tPD), skew (tPSKEW) and maximum data rate depend on the impedance of the device that is connected to the translator. The timing parameters listed in the data sheet assume that the output impedance of the drivers connected to the translator is less than 50 kΩ.

Enable Input (EN)

The PI4ULS3V204 has an Enable pin (EN) that provides tri-state operation at the I/O pins. Driving the Enable pin to a low logic level minimizes the power consumption of the device and drives the I/O VCCB and I/O VCCA pins to a high impedance state. Normal translation operation occurs when the EN pin is equal to a logic high signal. The EN pin is referenced to the VCCA supply and has overvoltage tolerant protection.

Power Supply Guidelines

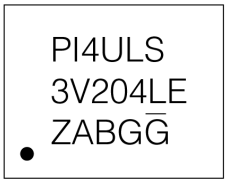
During normal operation, supply voltage VCCA can be greater than, less than or equal to VCCB. The sequencing of the power supplies will not damage the device during the power up operation. For optimal performance, 0.01µF to 0.1µF decoupling capacitors should be used on the VCCA and VCCB power supply pins. Ceramic capacitors are a good design choice to filter and bypass any noise signals on the voltage lines to the ground plane of the PCB. The noise immunity will be maximized by placing the capacitors as close as possible to the supply and ground pins, along with minimizing the PCB connection traces.

Part Marking

ZB Package

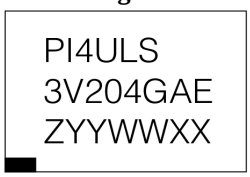
Z: Die Rev
YYWW: Date Code (Year & Workweek)
J: Assembly Site Code
G: Wafer Fab Site Code

L Package



Z: Die Rev
AB: Date Code (Year & Workweek)
G: Assembly Site Code
G: Wafer Fab Site Code
The Bar above 2nd “G” means Cu wire

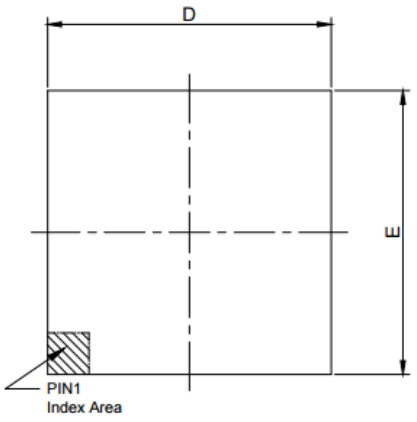
GA Package



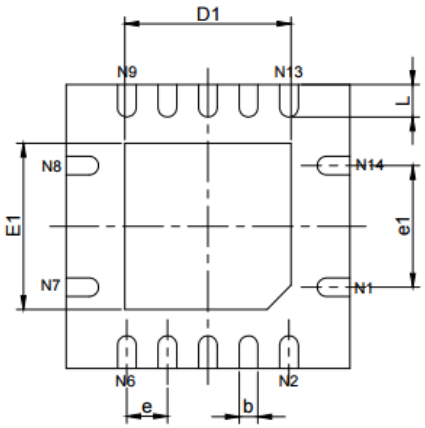
Z: Die Rev
YY: Year
WW: Workweek
1st X: Assembly Code
2nd X: Fab Code

Packaging Mechanical:

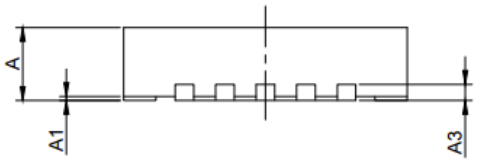
14-TQFN (ZB)



TOP VIEW



BOTTOM VIEW



SIDE VIEW

PKG. DIMENSIONS(MM)		
SYMBOL	Min	Max
A	0.80	0.90
A1	0.00	0.05
A3	0.20 REF	
D	3.42	3.58
E	3.42	3.58
D1	1.95	2.15
E1	1.95	2.15
b	0.20	0.30
e	0.50 TYP	
e1	1.50 TYP	
L	0.32	0.48

Note:
1. Ref: JEDEC MO-288B

PERICOM Semiconductor

DATE: 06/18/13

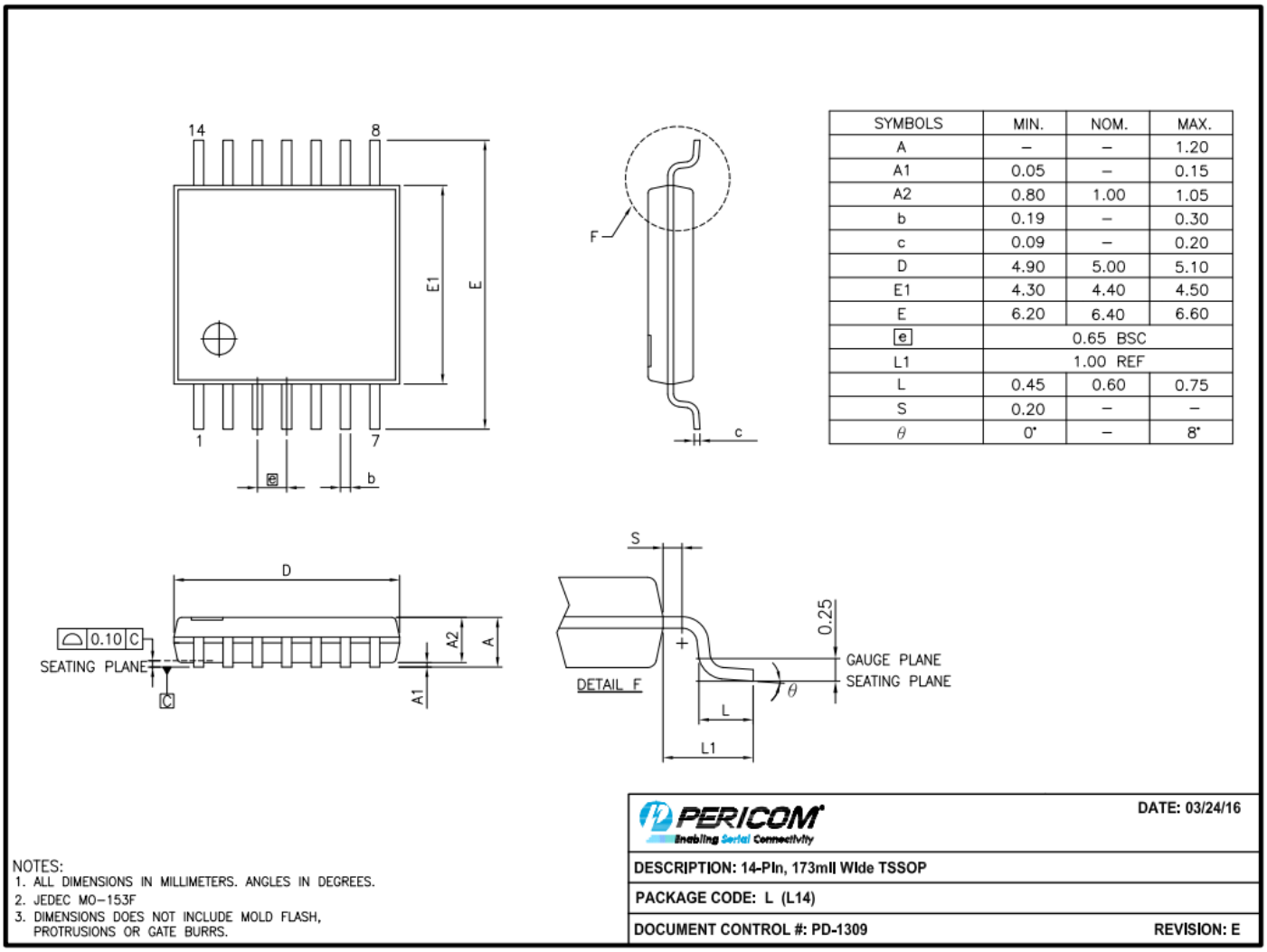
DESCRIPTION: 14-Pin, TQFN, 3.5x3.5

PACKAGE CODE: ZB (ZB14)

DOCUMENT CONTROL #: PD-2154 **REVISION: –**

13-0193

14-TSSOP (L)



SYMBOLS	MIN.	NOM.	MAX.
A	–	–	1.20
A1	0.05	–	0.15
A2	0.80	1.00	1.05
b	0.19	–	0.30
c	0.09	–	0.20
D	4.90	5.00	5.10
E1	4.30	4.40	4.50
E	6.20	6.40	6.60
e		0.65 BSC	
L1		1.00 REF	
L	0.45	0.60	0.75
S	0.20	–	–
θ	0°	–	8°

NOTES:
1. ALL DIMENSIONS IN MILLIMETERS. ANGLES IN DEGREES.
2. JEDEC MO-153F
3. DIMENSIONS DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

PERICOM Enabling Serial Connectivity

DATE: 03/24/16

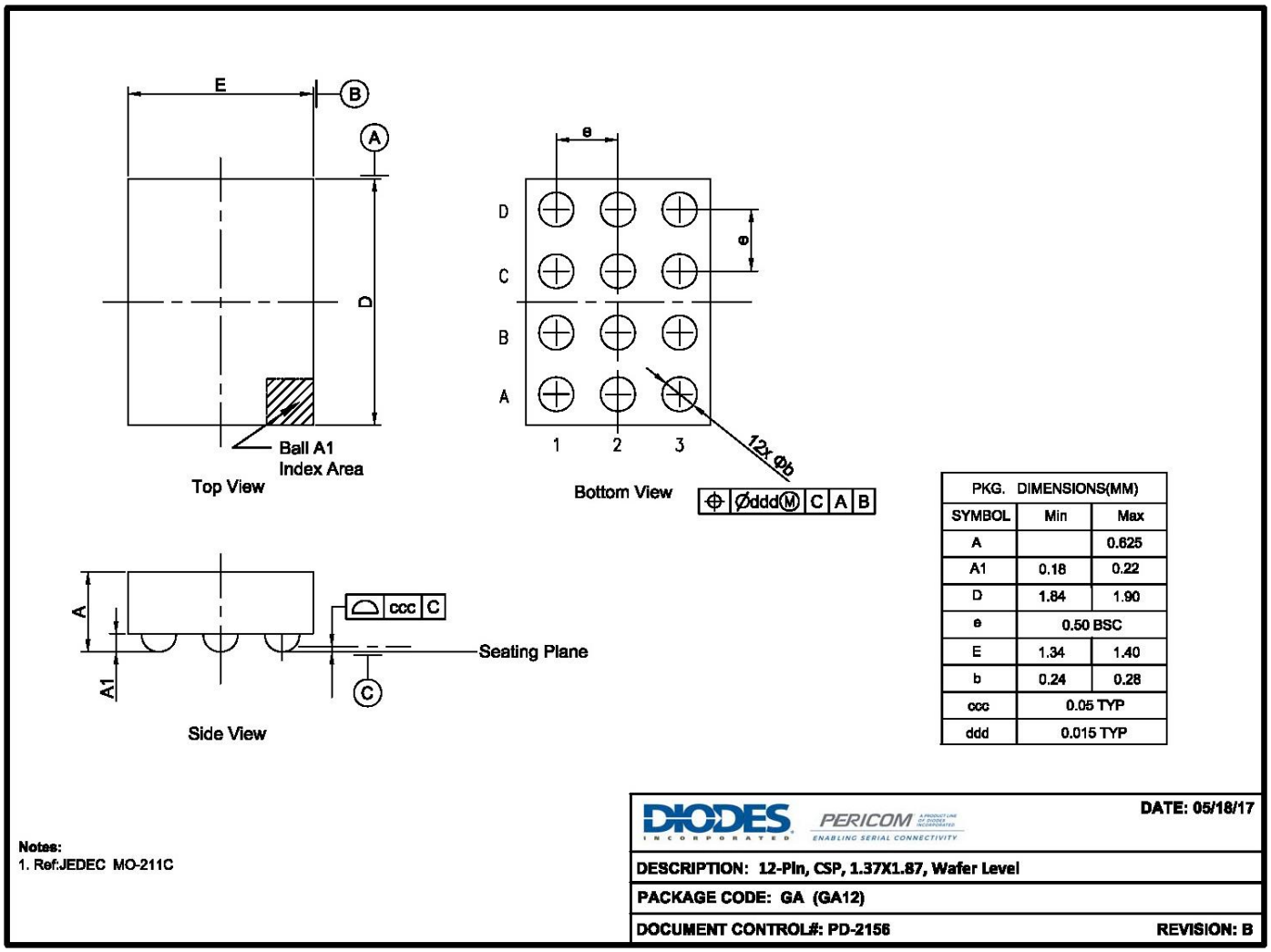
DESCRIPTION: 14-PIn, 173mll Wide TSSOP

PACKAGE CODE: L (L14)

DOCUMENT CONTROL #: PD-1309 REVISION: E

16-0060

12-CSP (GA)



PKG. DIMENSIONS(MM)		
SYMBOL	Min	Max
A		0.625
A1	0.18	0.22
D	1.84	1.90
e	0.50 BSC	
E	1.34	1.40
b	0.24	0.28
ccc	0.05 TYP	
ddd	0.015 TYP	

17-0369

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Part Number	Package Code	Package Description
PI4ULS3V204LEX	L	14-Pin,173 mil Wide (TSSOP)
PI4ULS3V204ZBEX	ZB	14-Pin, 3.5x3.5 (TQFN)
PI4ULS3V204GAEX	GA	12-Pin, 1.37x1.87, Wafer Level (CSP)
PI4ULS3V204ZBEX-13R	ZB	14-Pin, 3.5x3.5 (TQFN), Pin 1 orientation is Top Left

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. E = Pb-free and Green
5. X suffix = Tape/Reel
6. For packaging detail, go to our website at: https://www.diodes.com/assets/MediaList-Attachments/Diodes-Package-Information.pdf

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